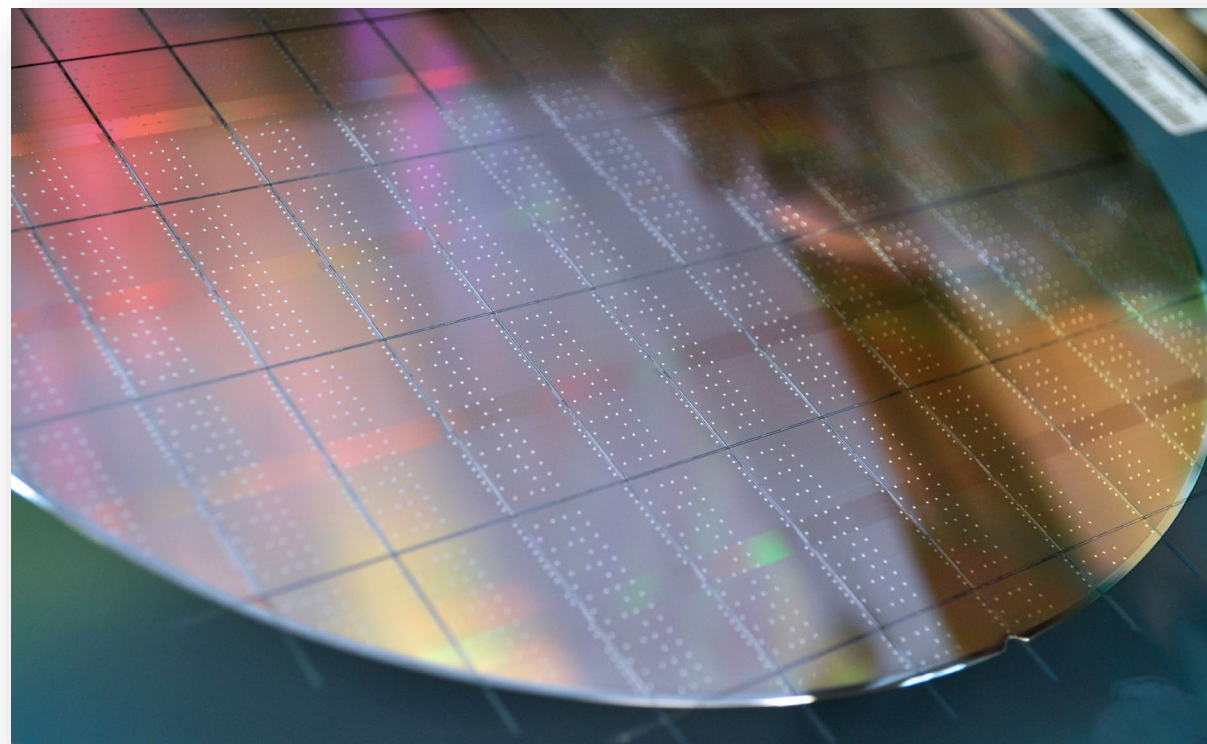


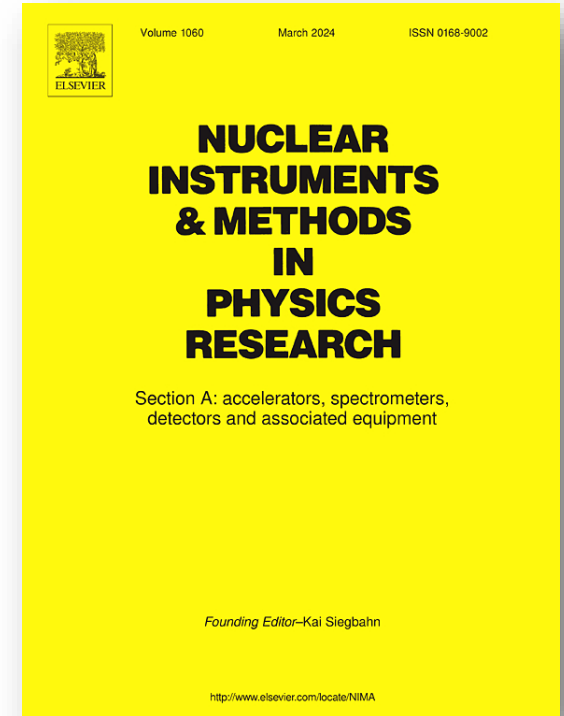
Development of technology for production of double-sided silicon microstrip modules for upgrade of NICA BM@N Silicon Tracking System



Sheremetev Aleksei
JINR LHEP



«In order to reconstruct all details of an interaction, not a single ionizing particle should be missed, and neutral particles, as much as possible, should be made to convert into observable ionizing ones».*



* **Erik H.M. Heijne**, "Particle physics experiments: From photography to integrated circuits", Nuclear Inst. and Methods in Physics Research, A 1055 (2023) 168466

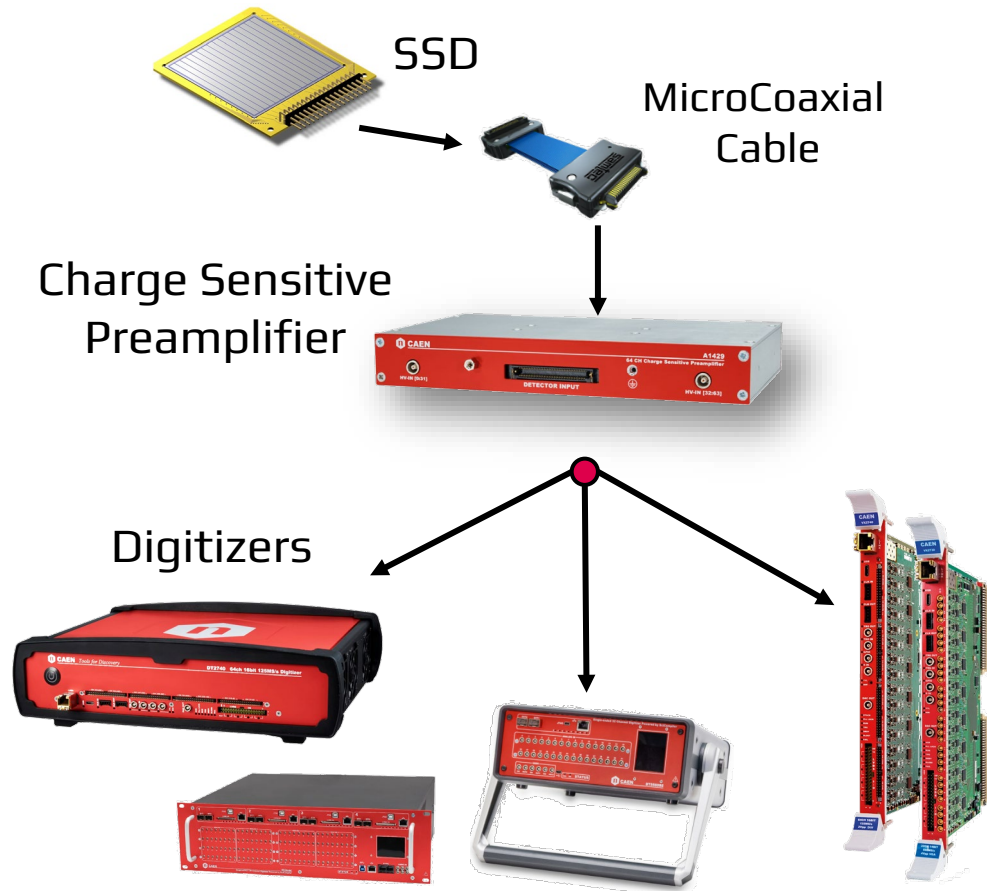
Some facts:

- In relativistic nuclear physics experiments involving heavy ion interactions, many more sensor elements are needed, compared to nuclear measurements, because of the much larger number of simultaneously produced secondary particles.
- At the NICA energies the collisions of Bi+Bi are expected to produce between 300 - 1000 particles per interaction that should be followed by the experimental setups.
- The size, the need for segmentation and complexity, and the reduction of power dissipation determines the development and used of customized Very Large Scale Integrated devices (VLSI), where billions of CMOS transistors are combined onto a single chip.

A detectors structure for physical experiments

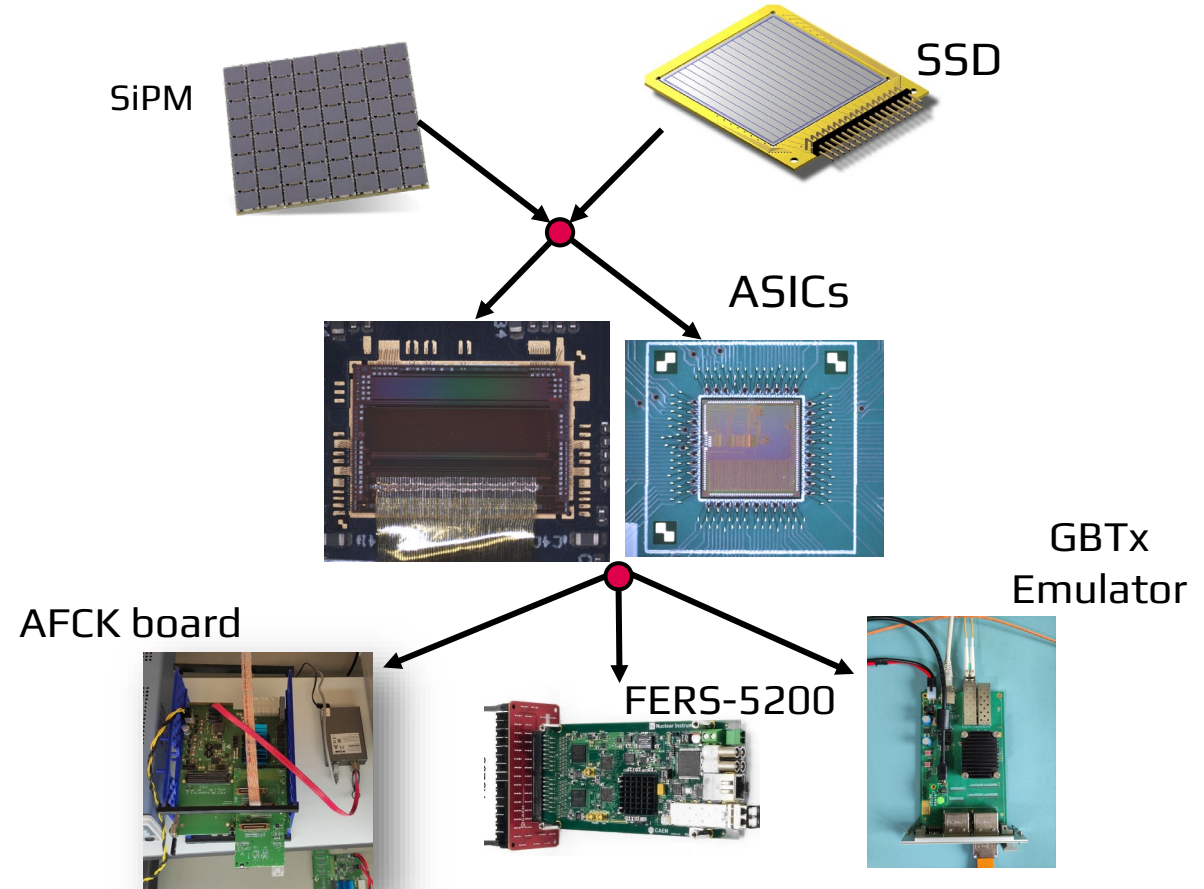
Method of standard readout blocks

The limit of spectroscopy channels ~300



The microelectronic methods

The limit of channels is design of detector

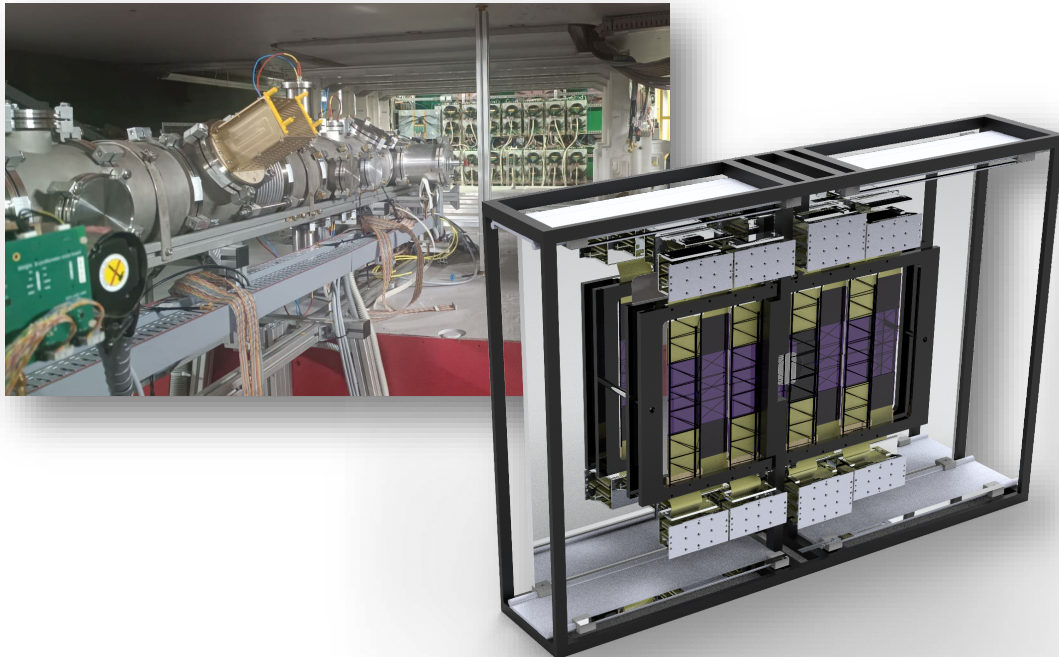


There is not off-the-shelf commercially available readout blocks technology that may offer a viable solution for the huge amount of channels demanded !

Two different construction of silicon tracing system

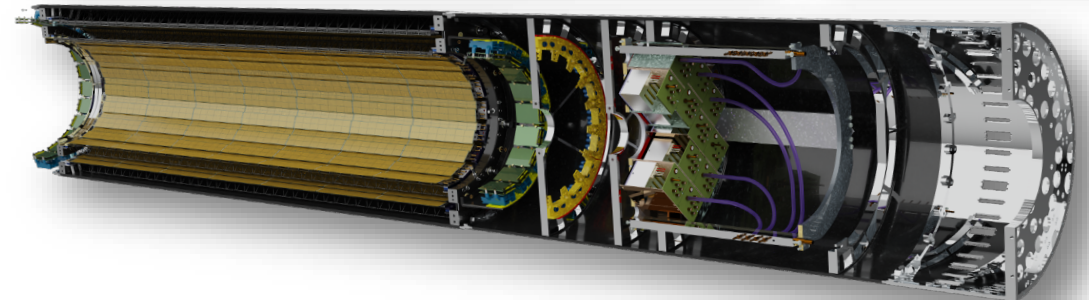
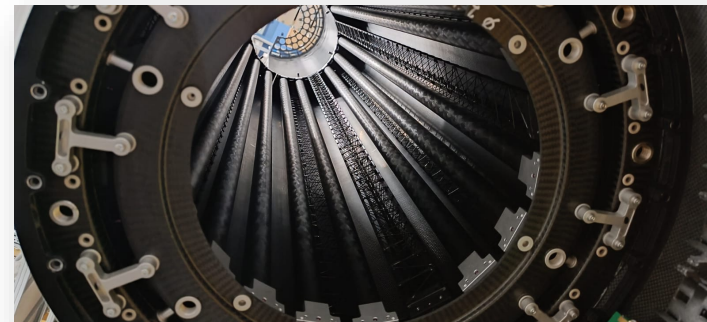
Fixed target experiment
BM@N STS

Needed numbers of channels $\sim 6 \times 10^5$
DSSD detectors

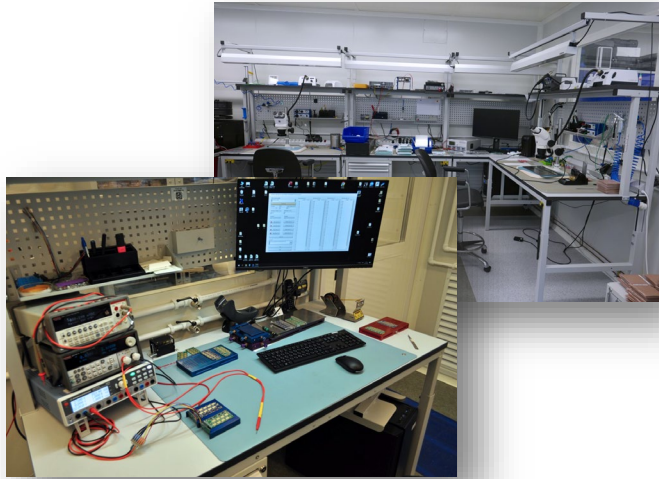


Collider experiment
MPD ITS

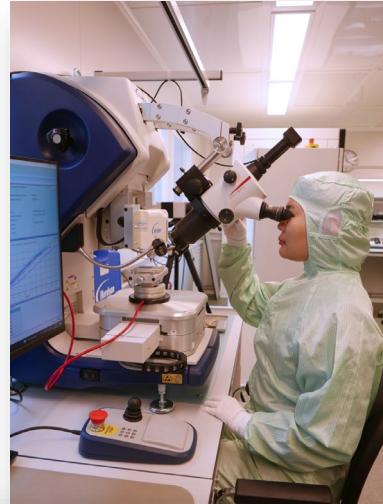
Needed numbers
of channels $\sim 4,3 \times 10^9$
MAPS detectors



LABs and equipment's



Team



The challenge for the customs electronics development based on ASIC devices

- The components availability

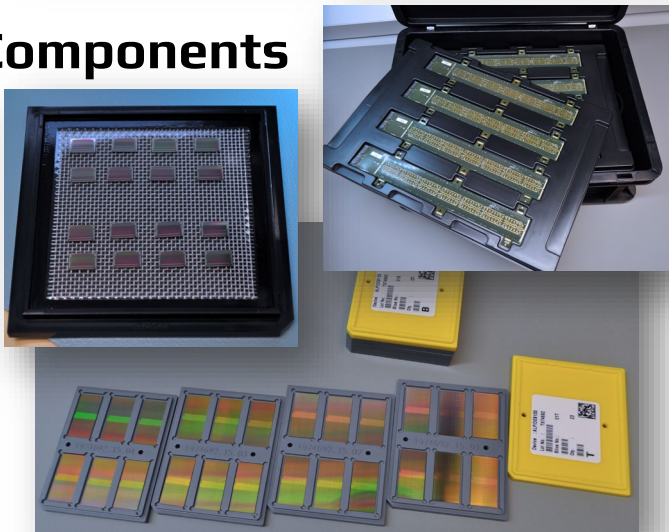
Assembly complexity

- Hundreds of thousands of connection soldering
- Precision requirement of the order of a few microns
- Resulting devices are not reparable

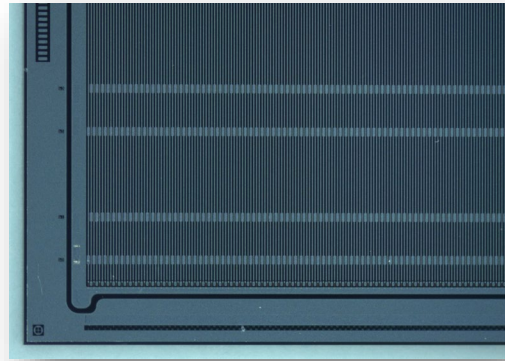
- Dealing with a huge amount of data to be transmitted and processed.



Components

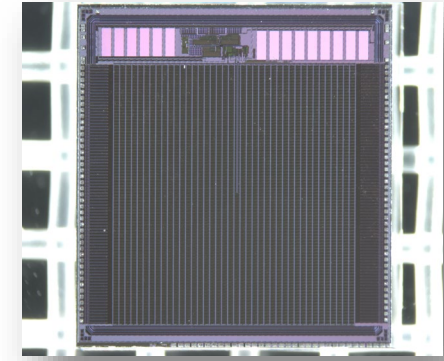
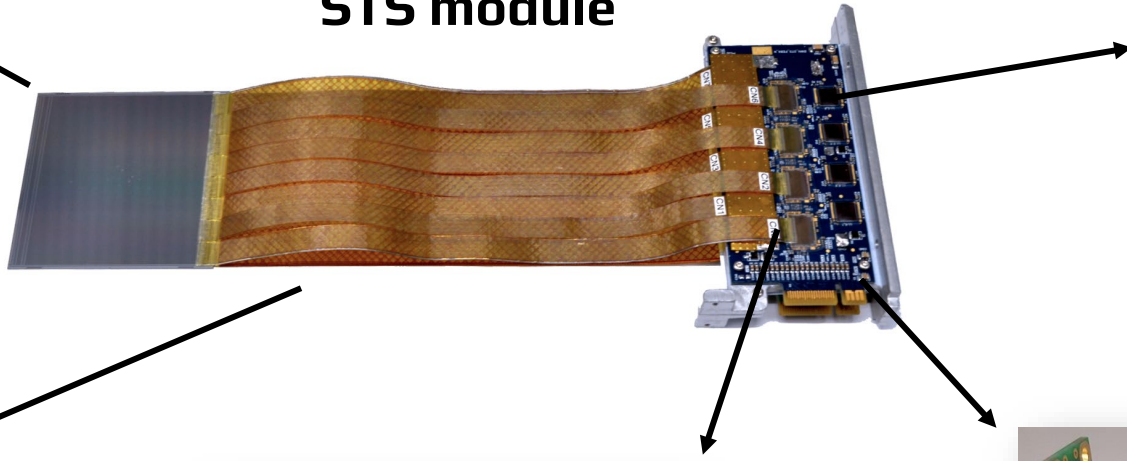


Components of silicon tracking module

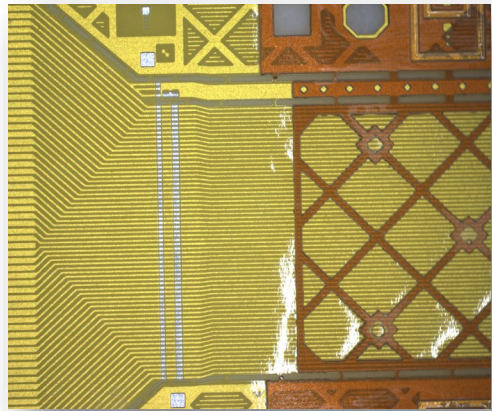


DSSD

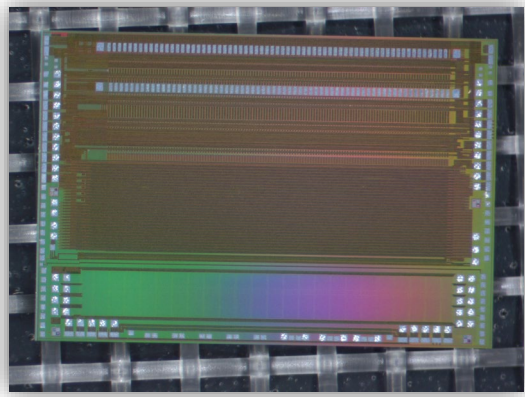
STS module



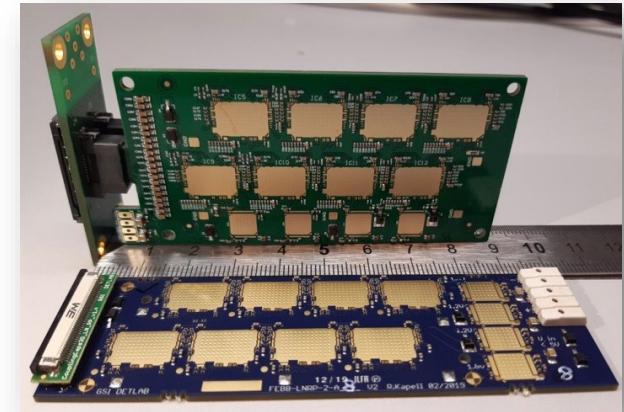
Low-drop voltage regulators(LDO)



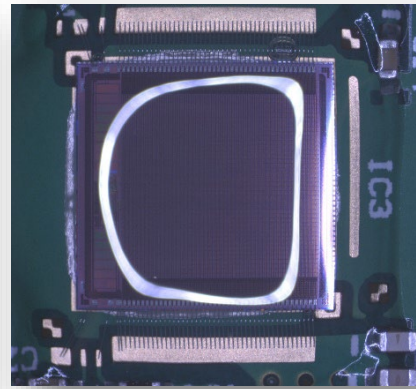
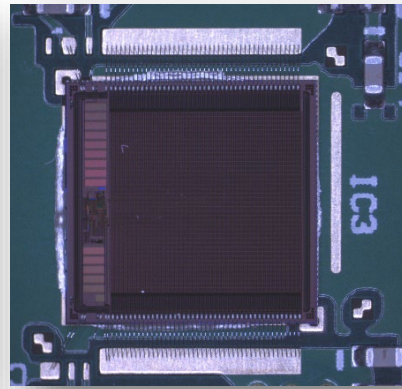
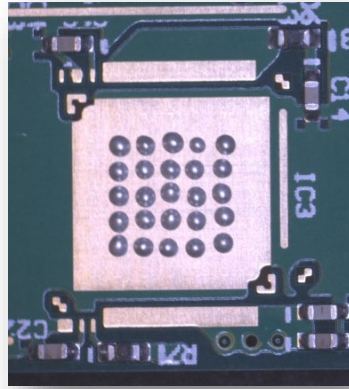
Aluminum-captone cable



ASIC STS-XYTER

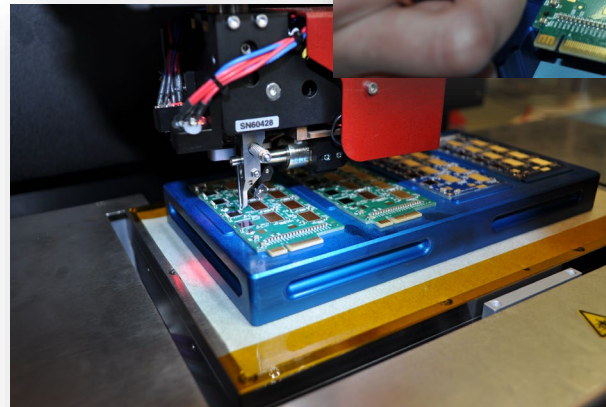
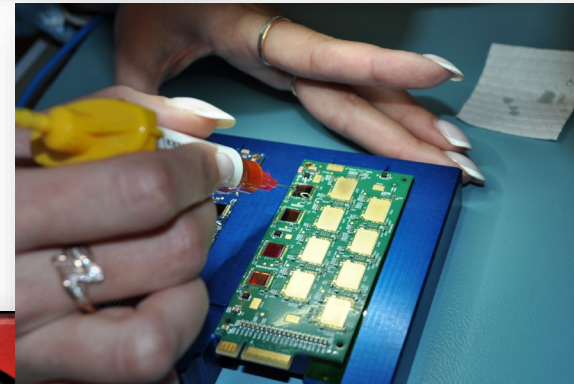


PCB FEB

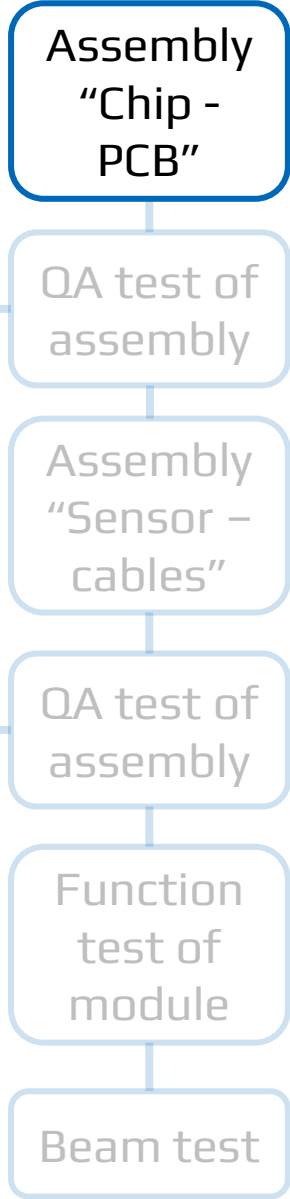


Technological stages of assembly ASIC
by Ultrasonic wire bonding :

- Glue and alignments ASICs on PCB
- Wire bonding
- Encapsulation of ASIC and wire



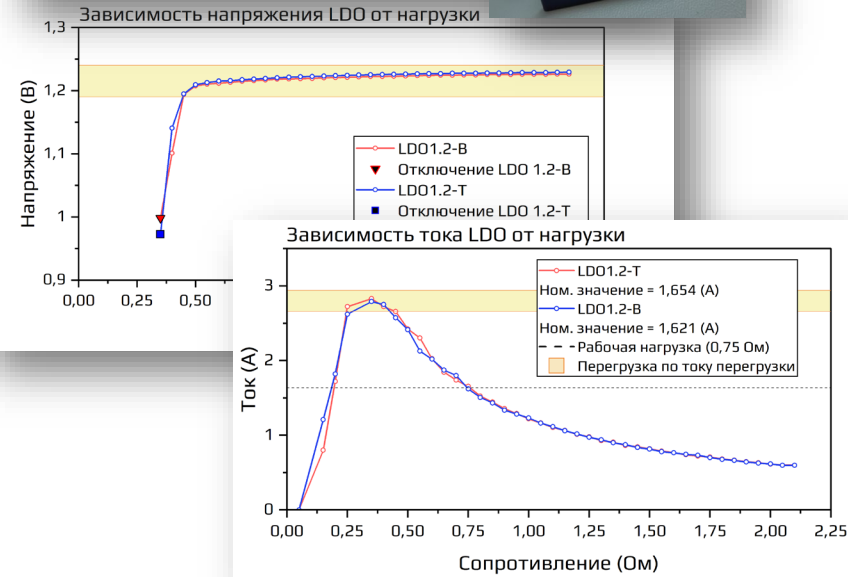
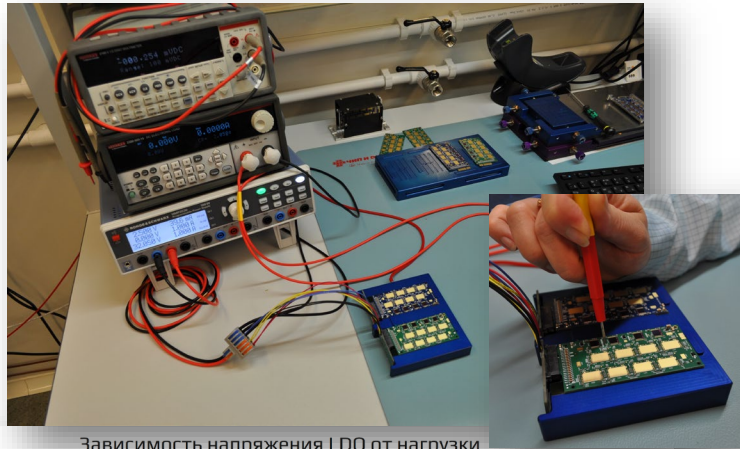
1st integration level



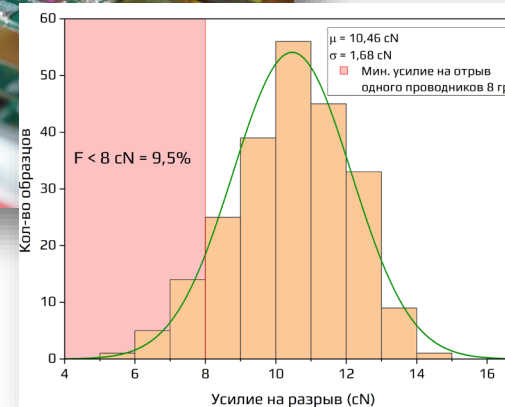
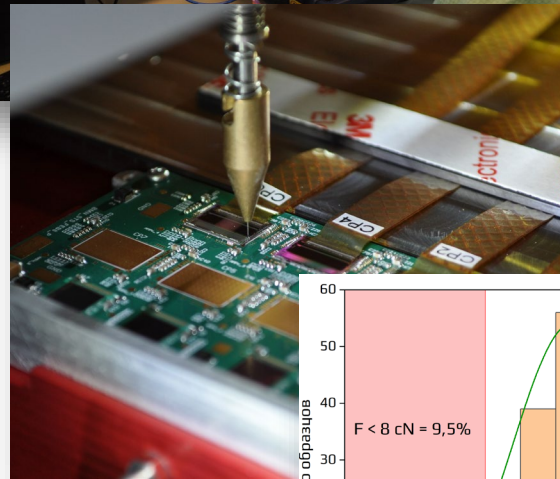
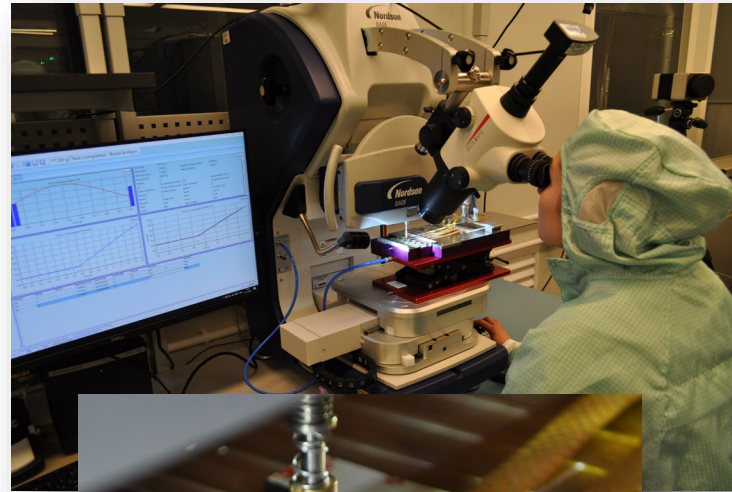
Save data to CMIS

Save data to CMIS

Functional test



Mechanical tests



Assembly "Chip - PCB"

Save data to CMIS

QA test of assembly

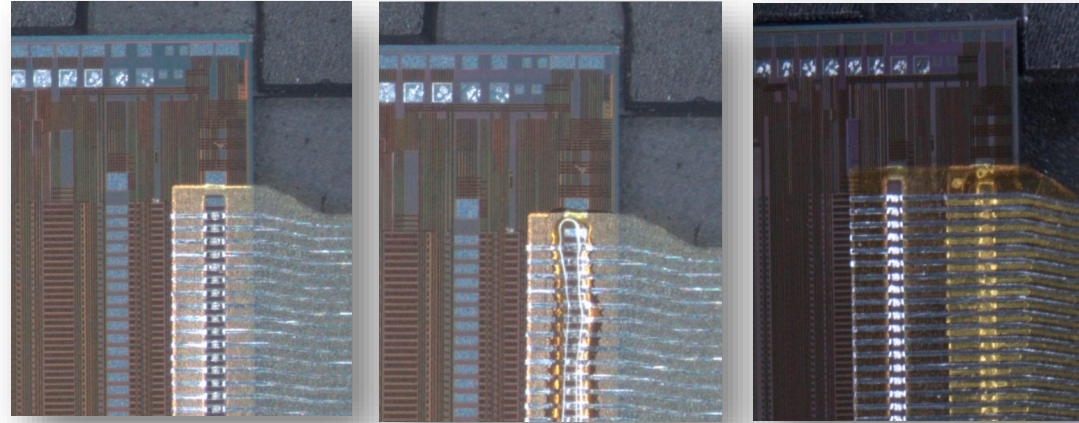
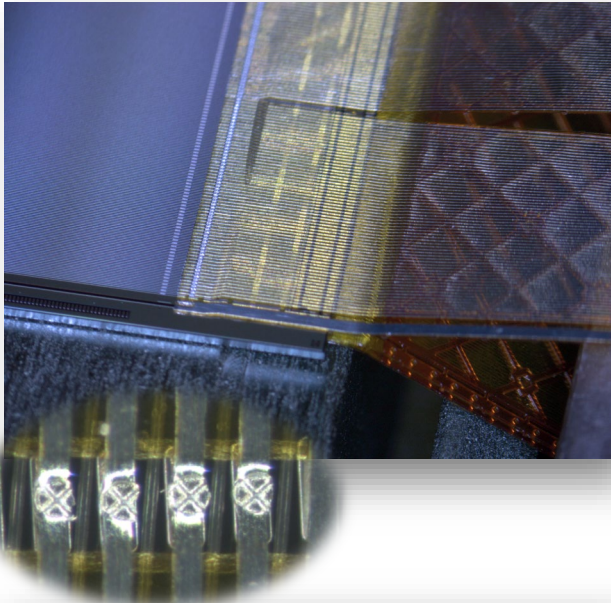
Assembly "Sensor - cables"

Save data to CMIS

QA test of assembly

Function test of module

Beam test



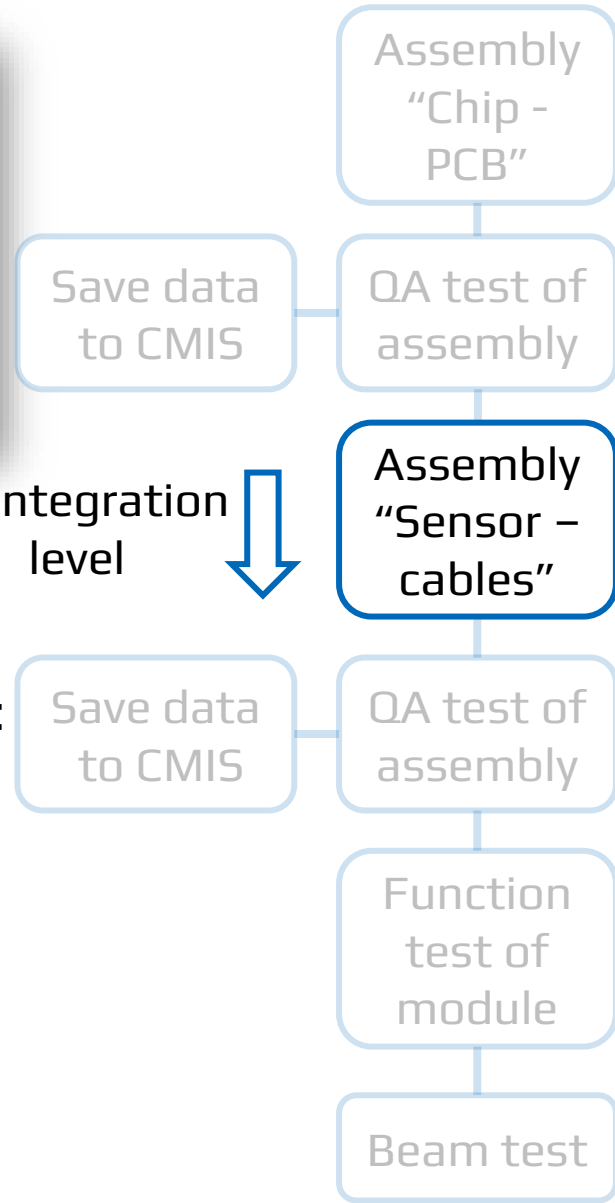
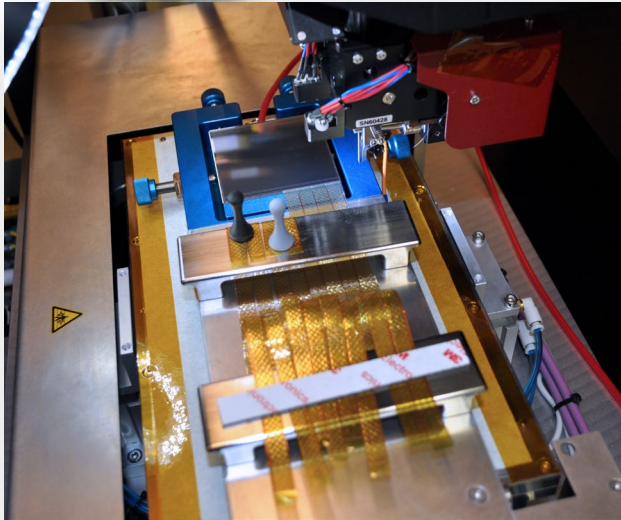
2nd integration level



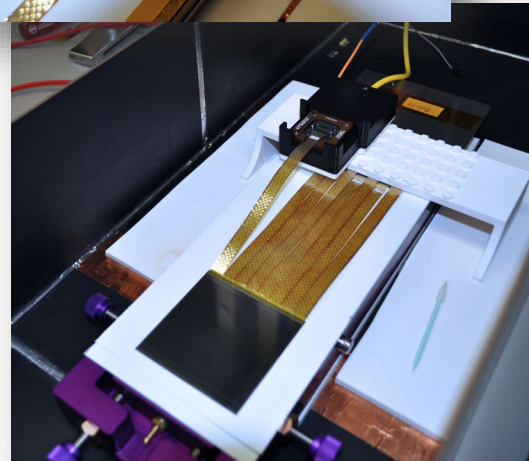
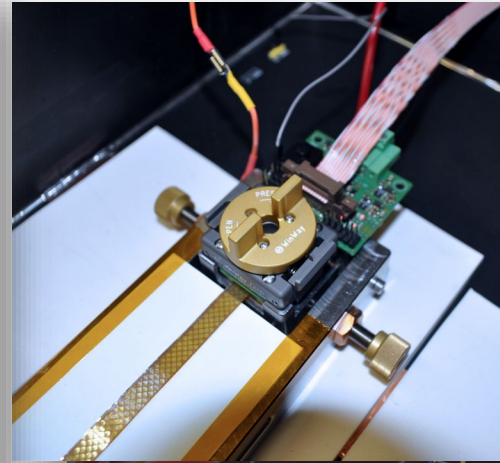
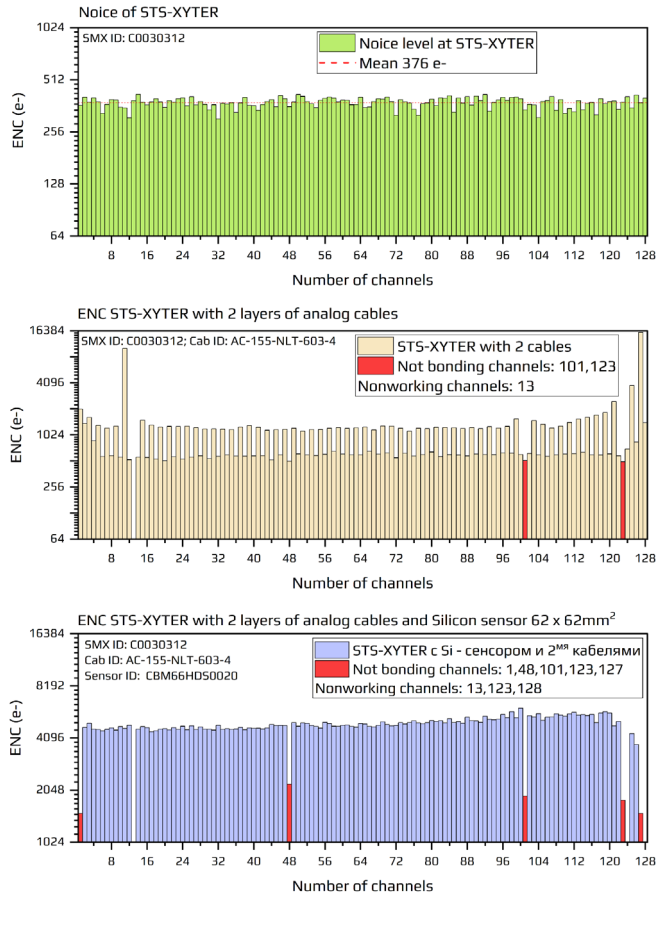
Technological stages of assembly

ASIC and Si - sensor by Ultrasonic TAB bonding :

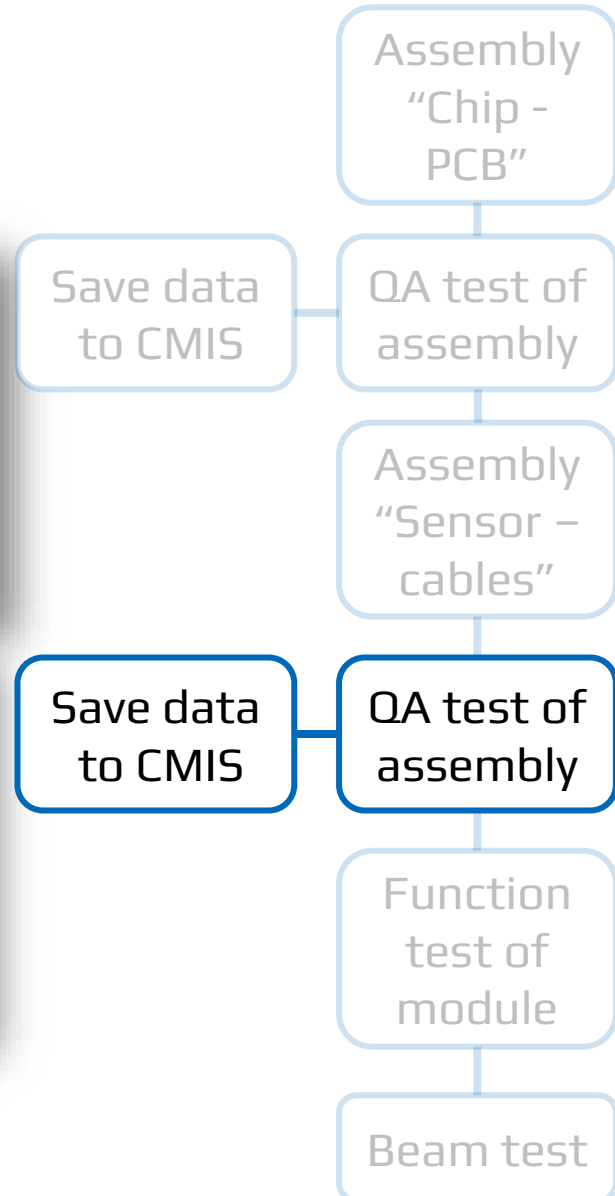
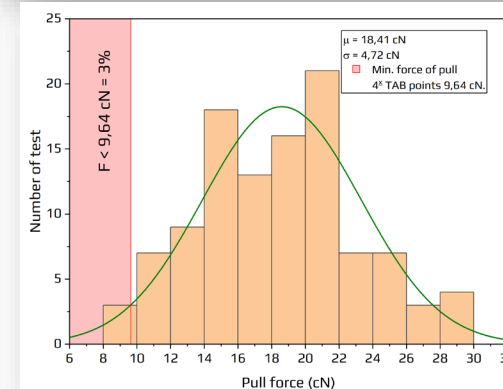
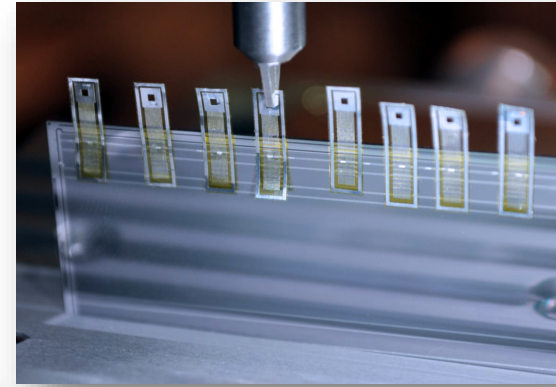
- Fix and alignments ASICs on jig with cable
- 1st TAB bonding process
- Encapsulation of ASIC and bond points
- Assembly second layer of cable



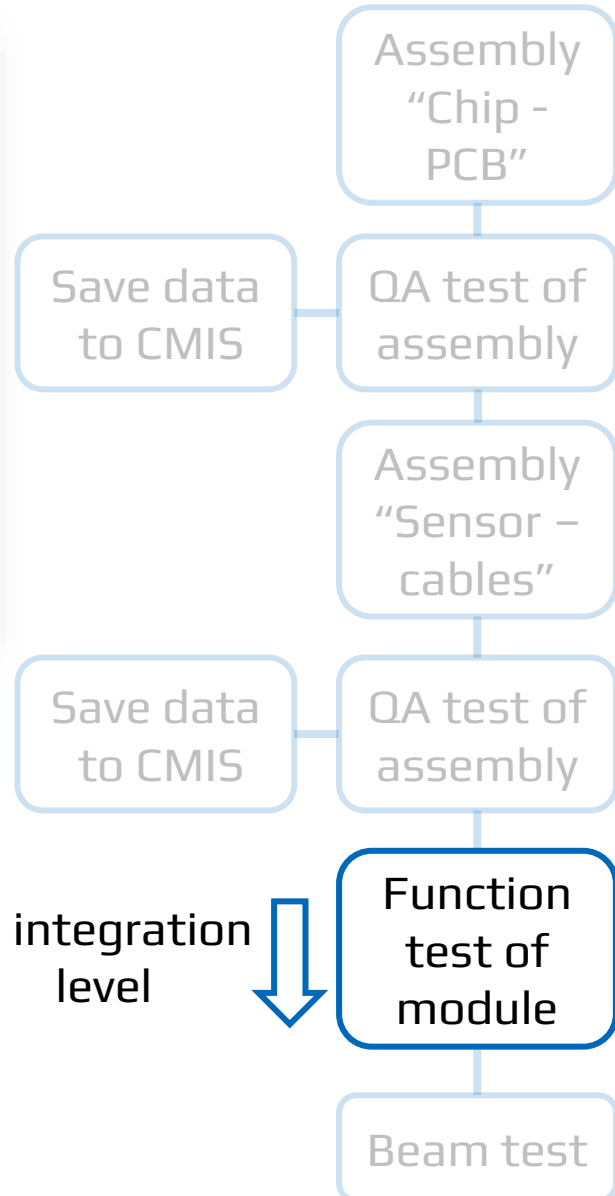
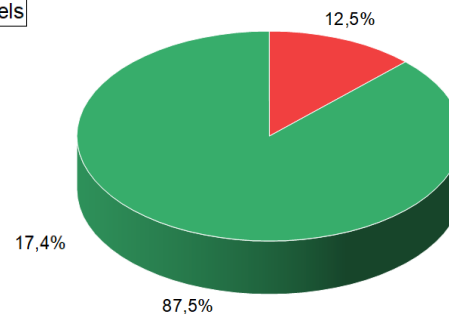
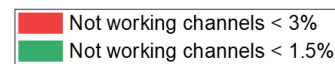
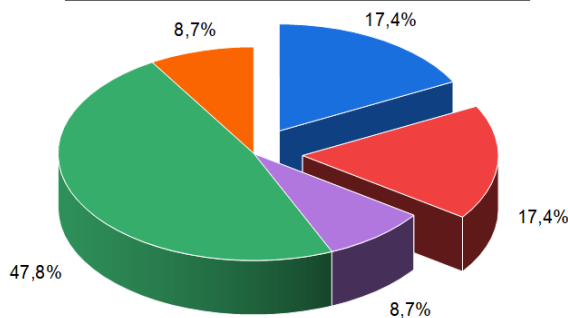
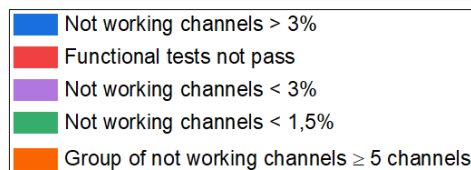
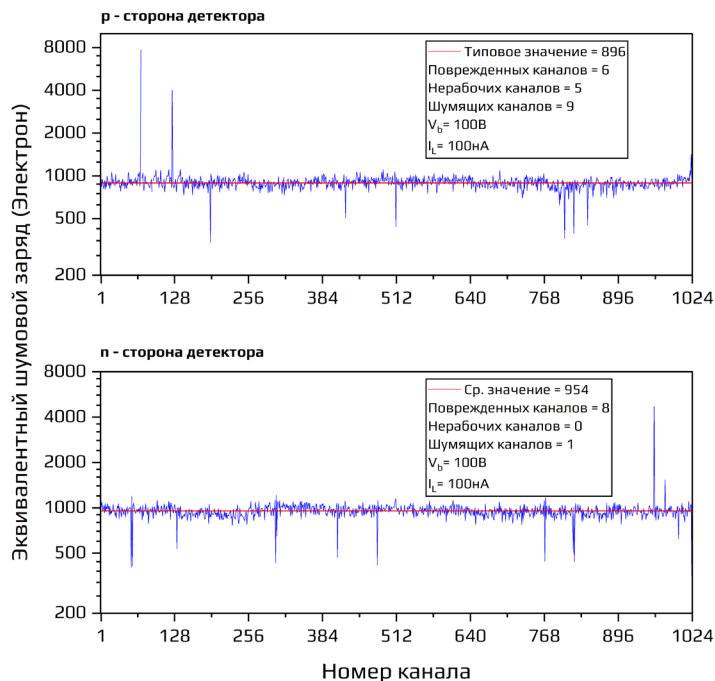
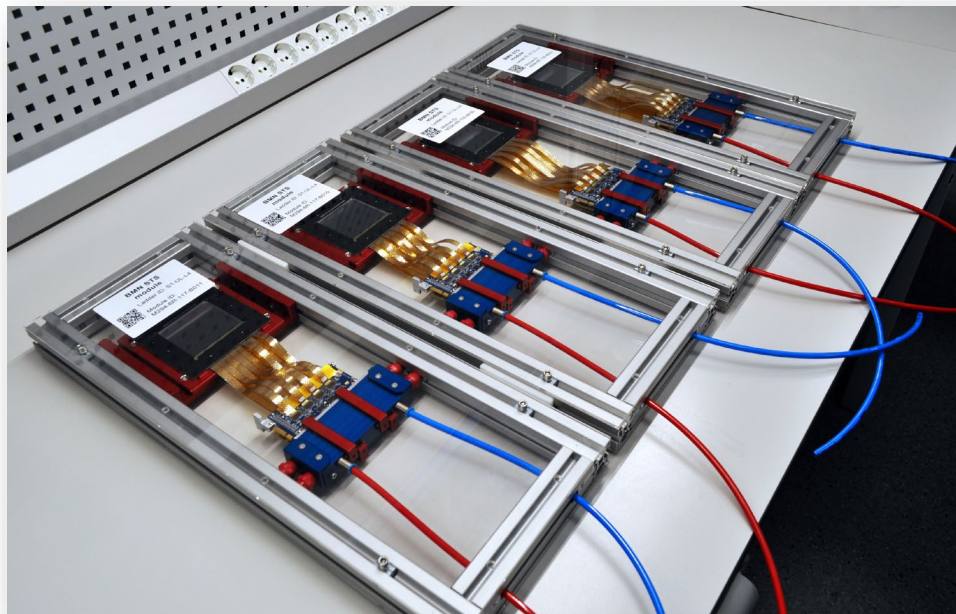
Functional test



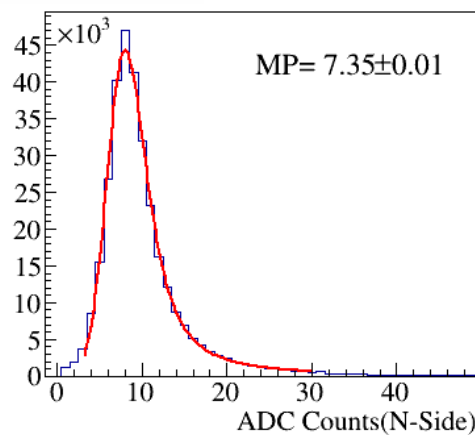
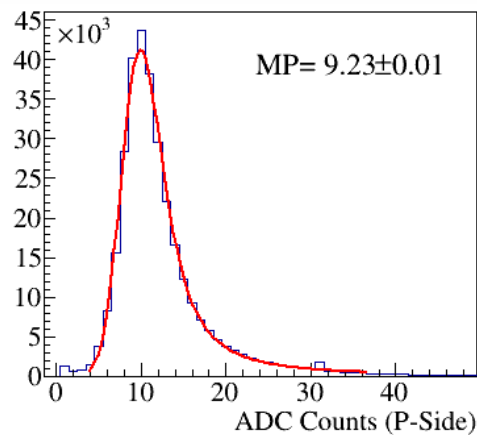
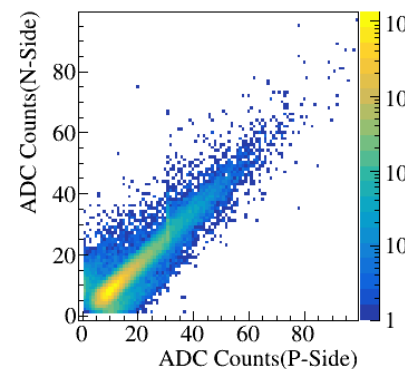
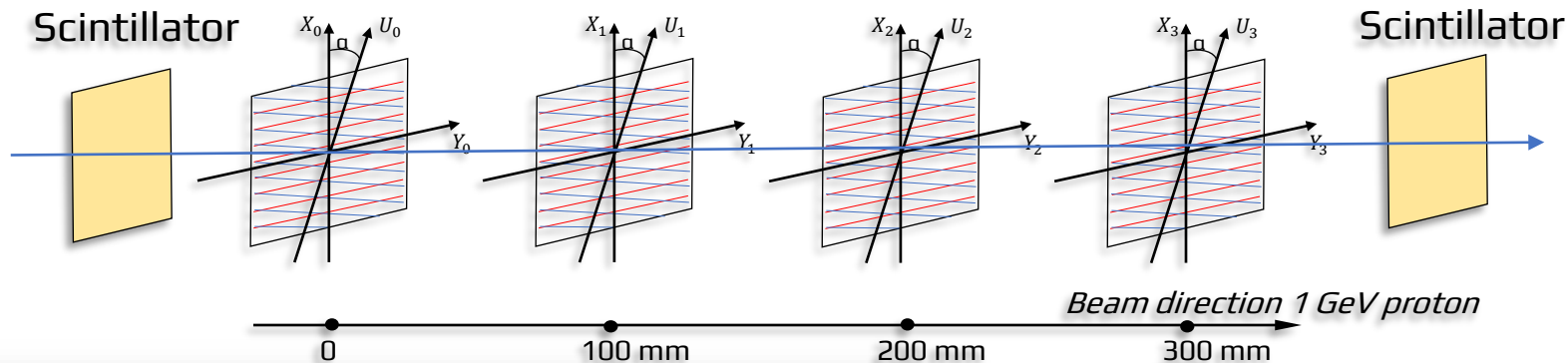
Mechanical tests



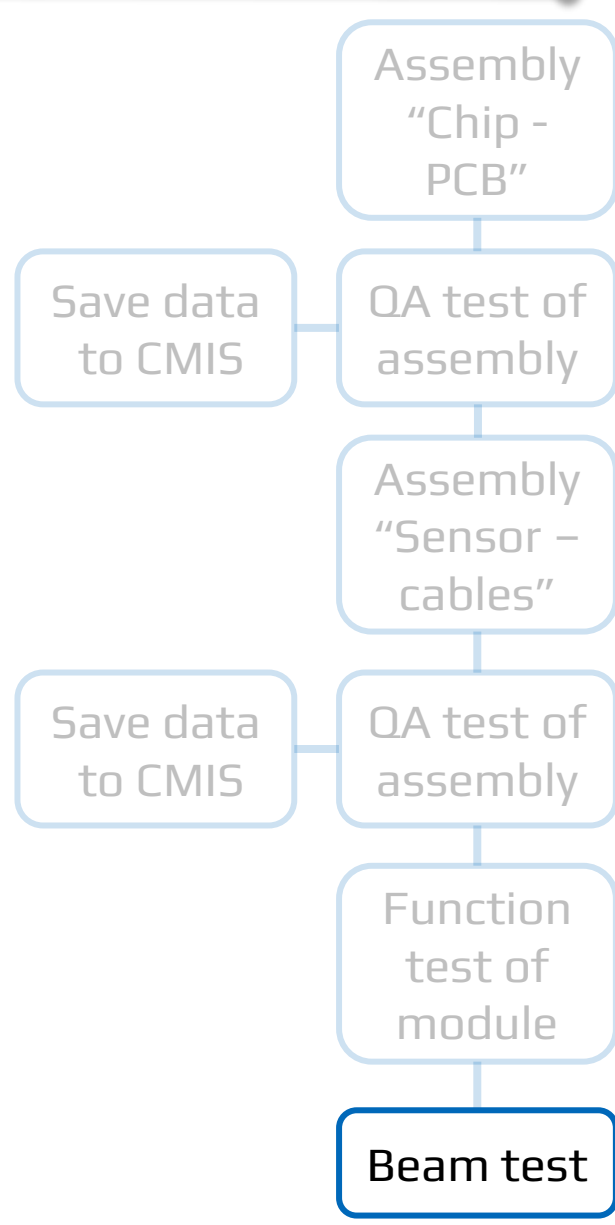
Module ID	Size of sensor	Cable length	Nb. ch.
B033	62	155	26
B011	62	117	14
B008	62	117	10
B009	62	117	7
B032	62	155	56
B034	62	155	23



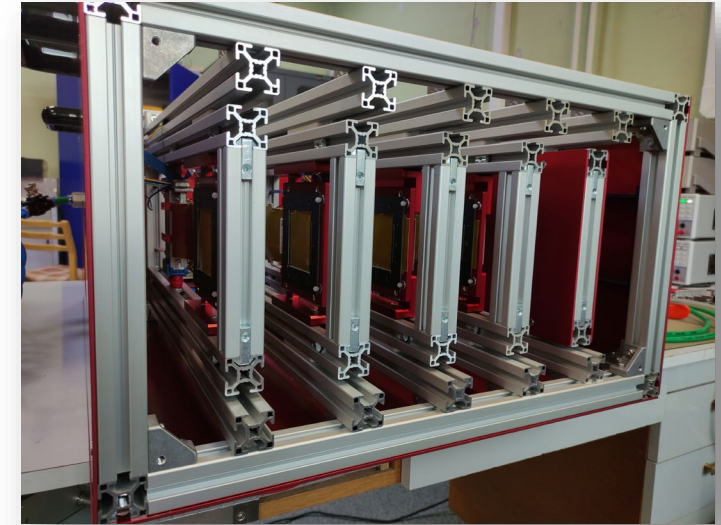
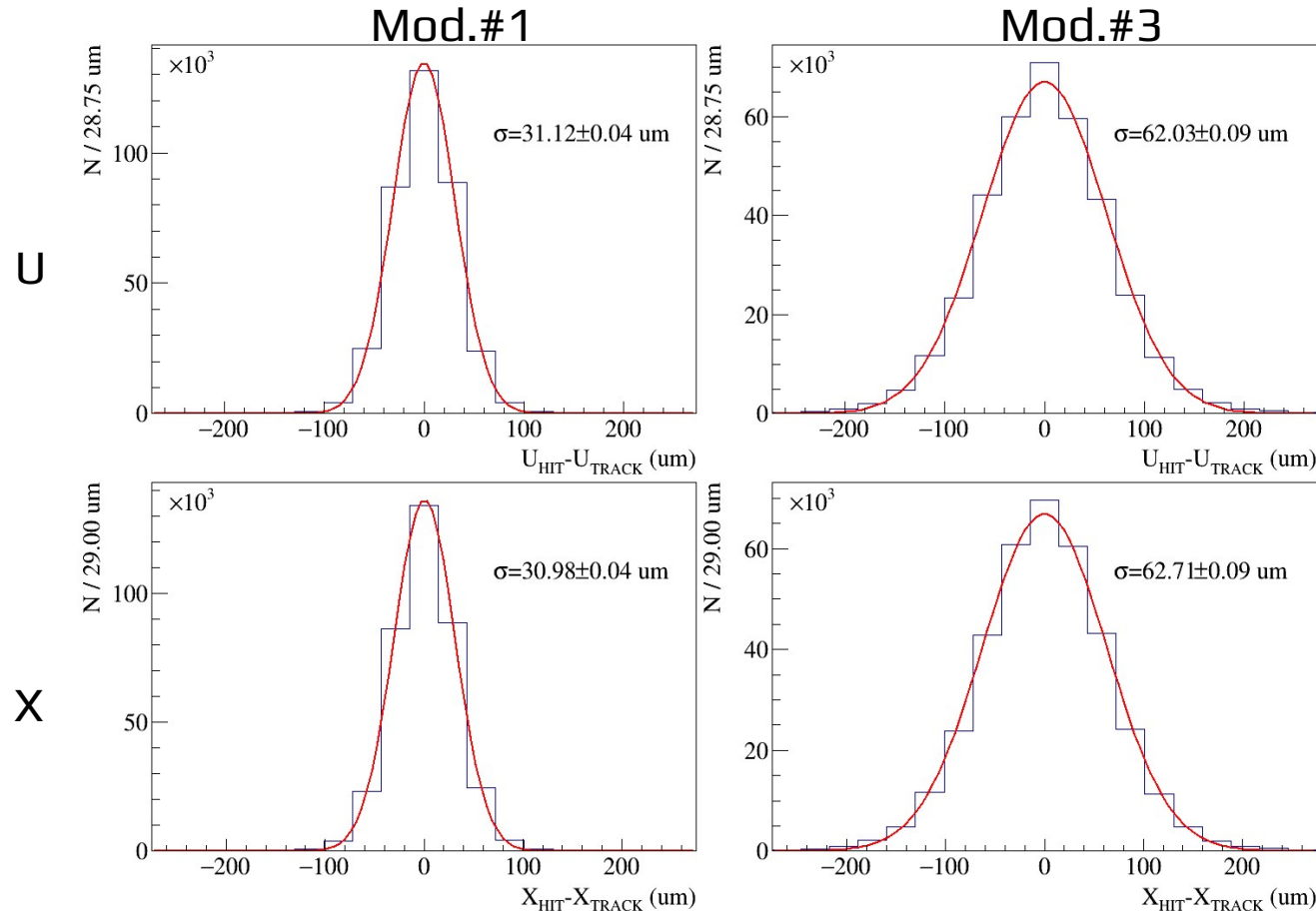
Results of the in-beam tests with 1 GeV proton



Cluster Amplitudes for P and N sides



STS modules and readout electronics were tested at proton beam in Gatchina:



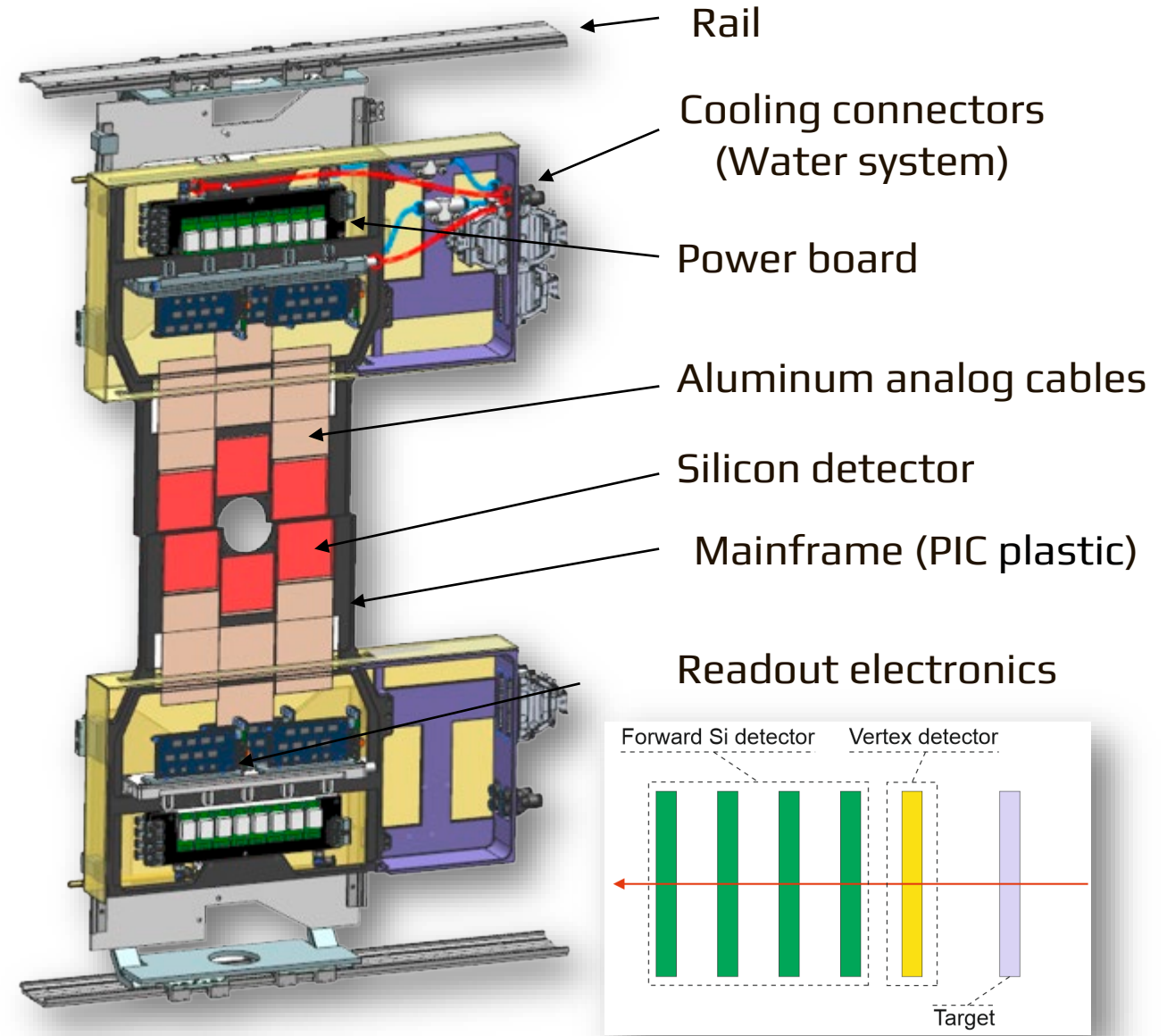
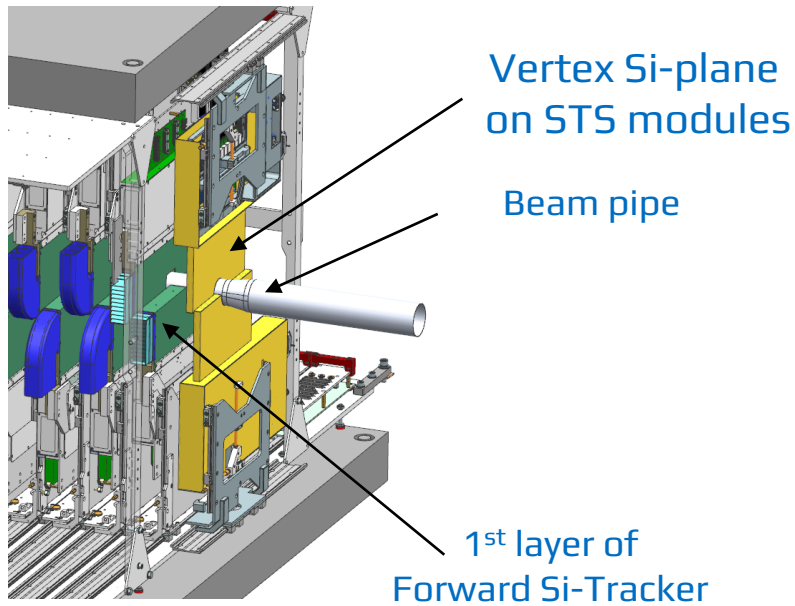
Telescope with 4 modules

- **Signal/Noise > 23;**
- **Thresholds 4600 - 6300 e⁻;**
- **Gain discrepancy < 15%;**
- **Spatial resolution $17 \pm 0.4 \mu\text{m}$;**
- **Efficiency > 99%** (for the areas without nonworking channels)

Residuals for 1-str. clusters Mod.#1 (left) and #3 (right)

Conceptual design of vertex Si-plane

- **Total number of channels:** 12k channels
- **Pitch:** 58 μm , 7.5° stereo-angle;
- **Distance from target to STS station:** 115 mm
- **Thickness of sensor:** 320 μm \pm 15 μm ;
- **Mainframe for sensor:** Alumina Ceramic Al_2O_3
- **Material per station** \approx 0.3% – 1.5% X_0



- Have been organized lab for custom production detectors with microelectronics components.
- Trained staff and prepare technological map of production and quality assurance tests
- Organized collaboration with China university CCNU and USTC for production of modules.

